

Tiny Tail Flash: Near-Perfect Elimination of Garbage Collection Tail Latencies in NAND SSDs

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GC-Induced Tail Latencies

Google: Taming The Long Latency Tail - When More Machines Equals Worse Results

“[If a] read is stuck behind an erase, [it] must wait 10s of ms, ... a **100x** increase in latency variance”

Why SSDs don't perform

From their earliest days, people have reported that SSDs were not providing the performance they expected. As SSDs age, for instance, they get slower. Here's why.

Why it's hard to meet SLAs with SSDs

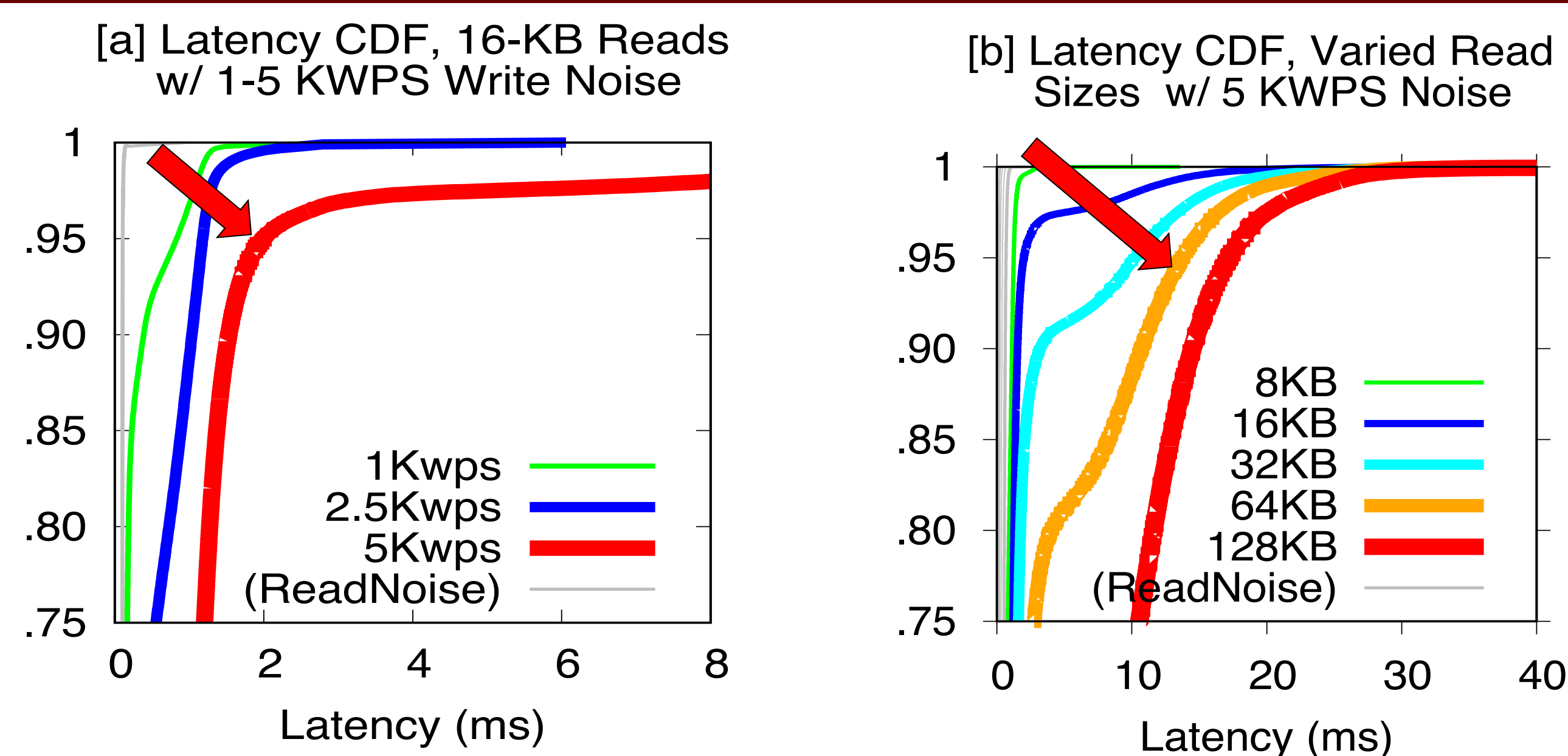


Figure 1: GC-Induced Tail Latency

More frequent GCs block incoming reads (from more intense random writes) and create longer tail latencies.

As read size increases, the probability of one of the pages being blocked by GC also increases.

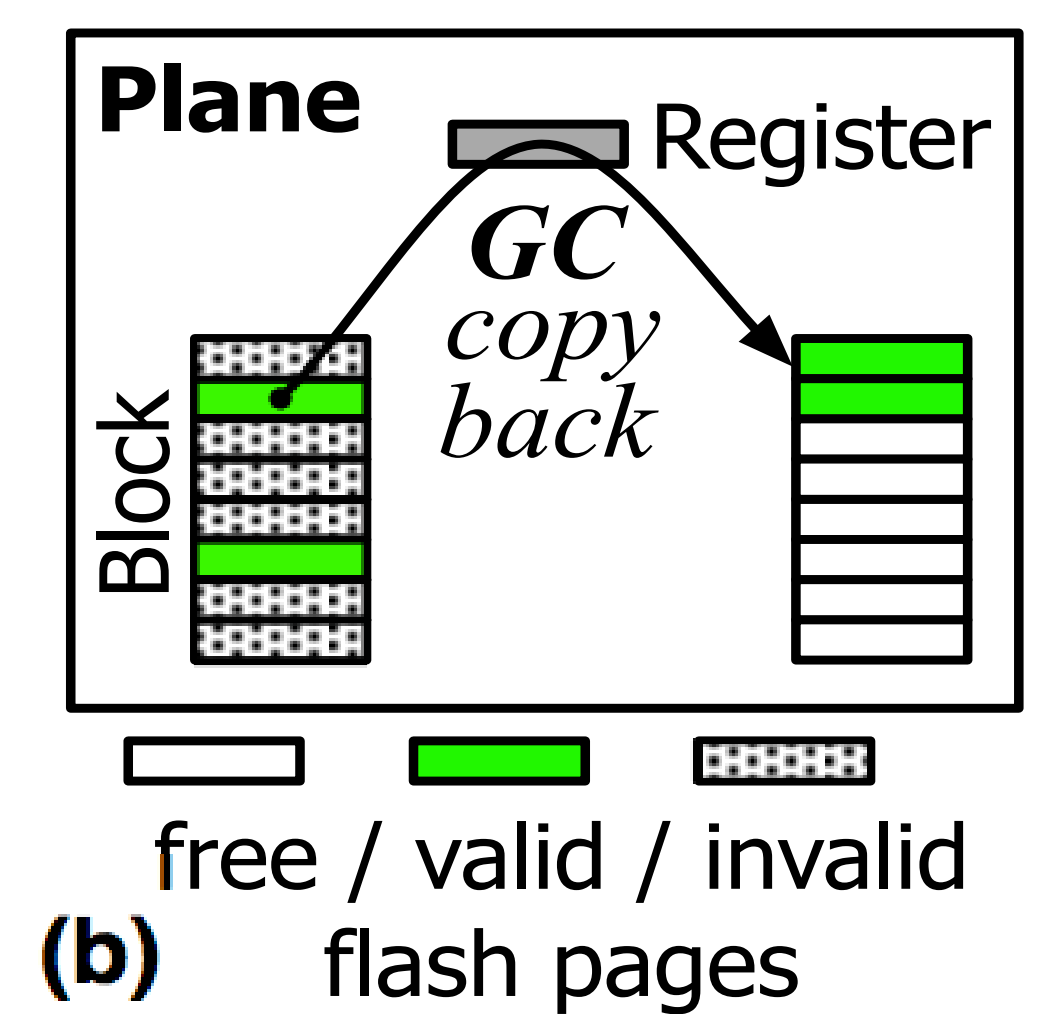


Figure 2: Example of GC Copyback

GC has to copy forward all valid pages to new block before erasing old block.

Tiny Tail Flash (π Flash) Architecture

Leverage three major SSD technological advancements:

- Increasing power and speed of today's flash controller
- Redundant Array of Independent NAND (RAIN)
- “Super capacitor” backed RAM

- 1 Plane-Blocking GC(PB): block GCing-plane (finer granularity)
- 2 GC-Tolerant Read(GTR): XOR to reconstruct page blocked by GC
- 3 GC-Tolerant Flush(GTF): store write blocked by GC in RAM
- 4 Rotating GC(RGC): limit GCing-plane to 1 per RAID group

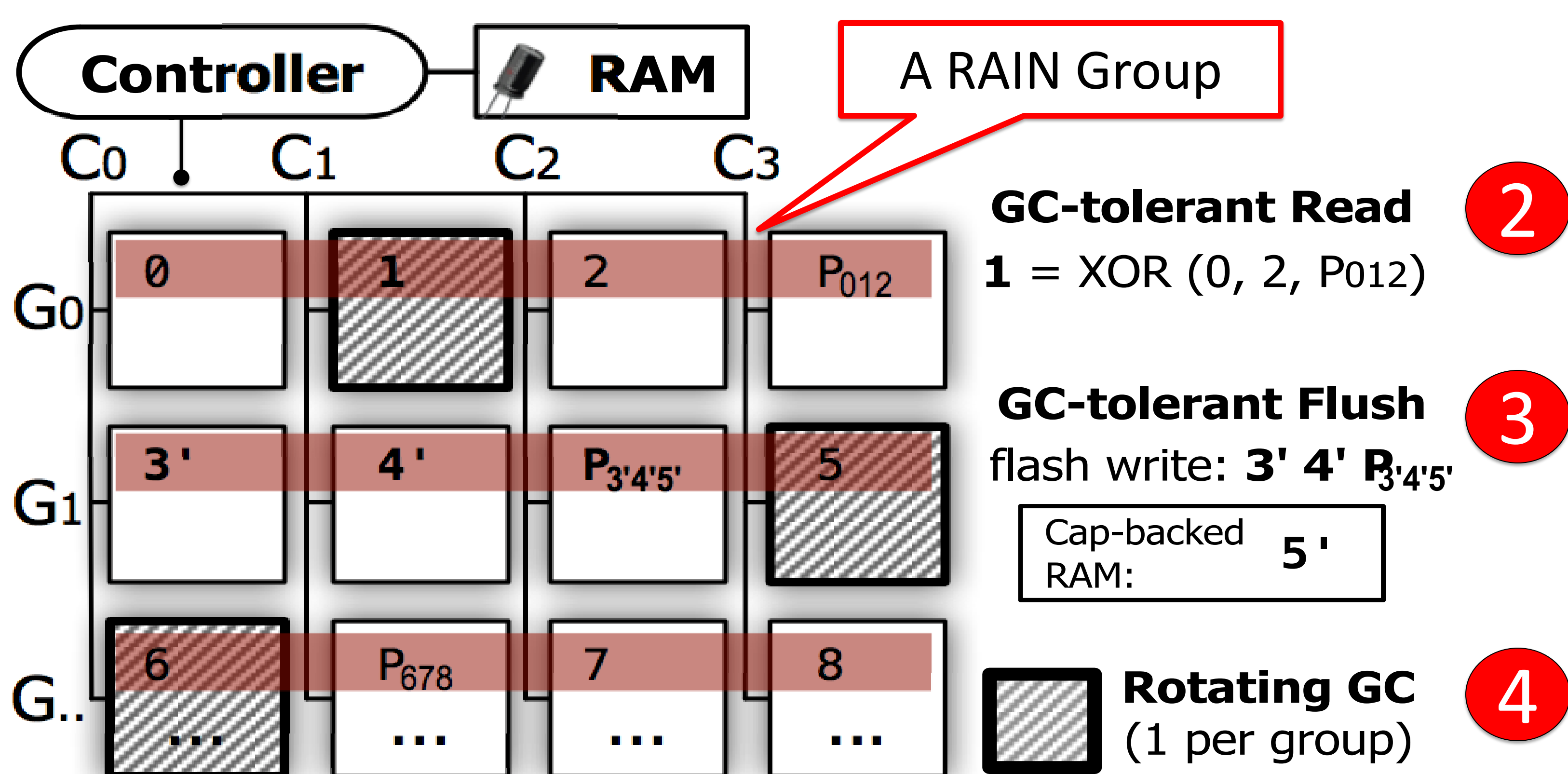


Figure 3: ttFlash Architecture

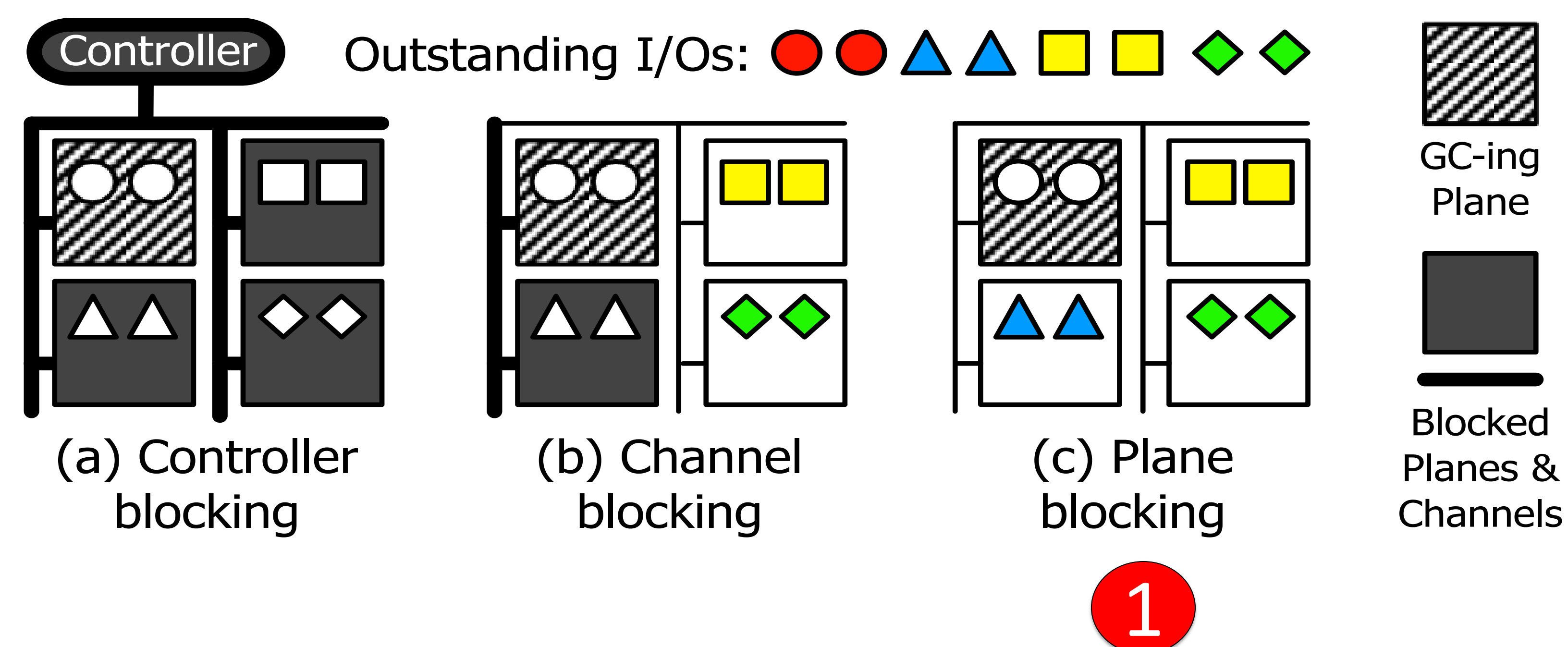


Figure 4: Various Levels of GC-Blocking

Experiment Results

Evaluation with 6 real-world traces (Windows servers)

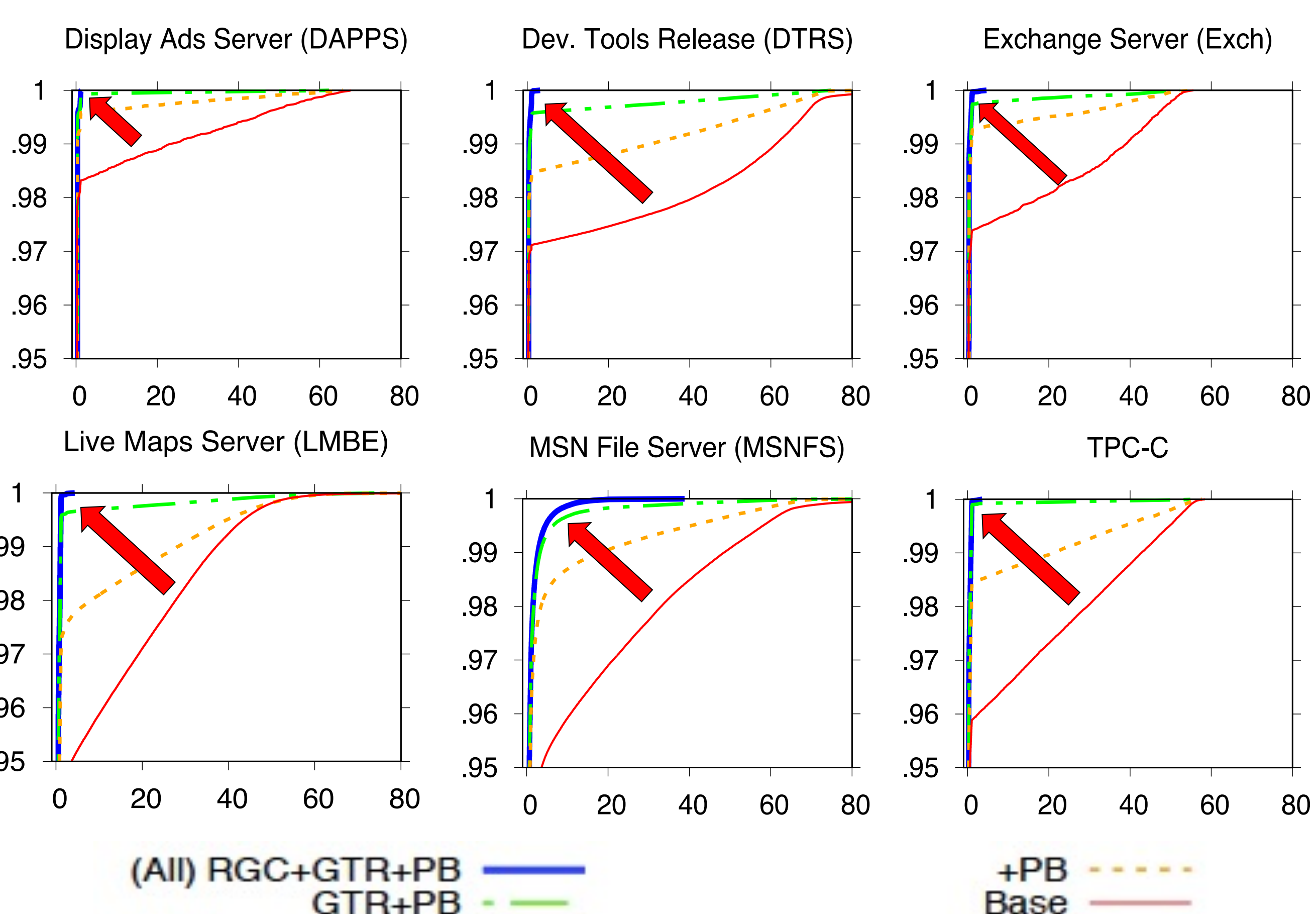


Figure 5: CDF of Read Latencies

Percentile	DAP	DTRS	EXCH	LMBE	MSN	TPCC
99.99 th	1.0x	1.2	1.2	2.0	1.0	2.6
99.9 th	1.0x	1.0	1.0	1.0	1.0	1.0
99 th	1.0x	1.0	1.1	1.0	1.0	1.0

Table 1: ttFlash vs. NoGC

99 – 99.9th: < 1.1x for ttFlash and < 138.2x for Base
99.99th: < 2.6x for ttFlash and < 91.9x for Base

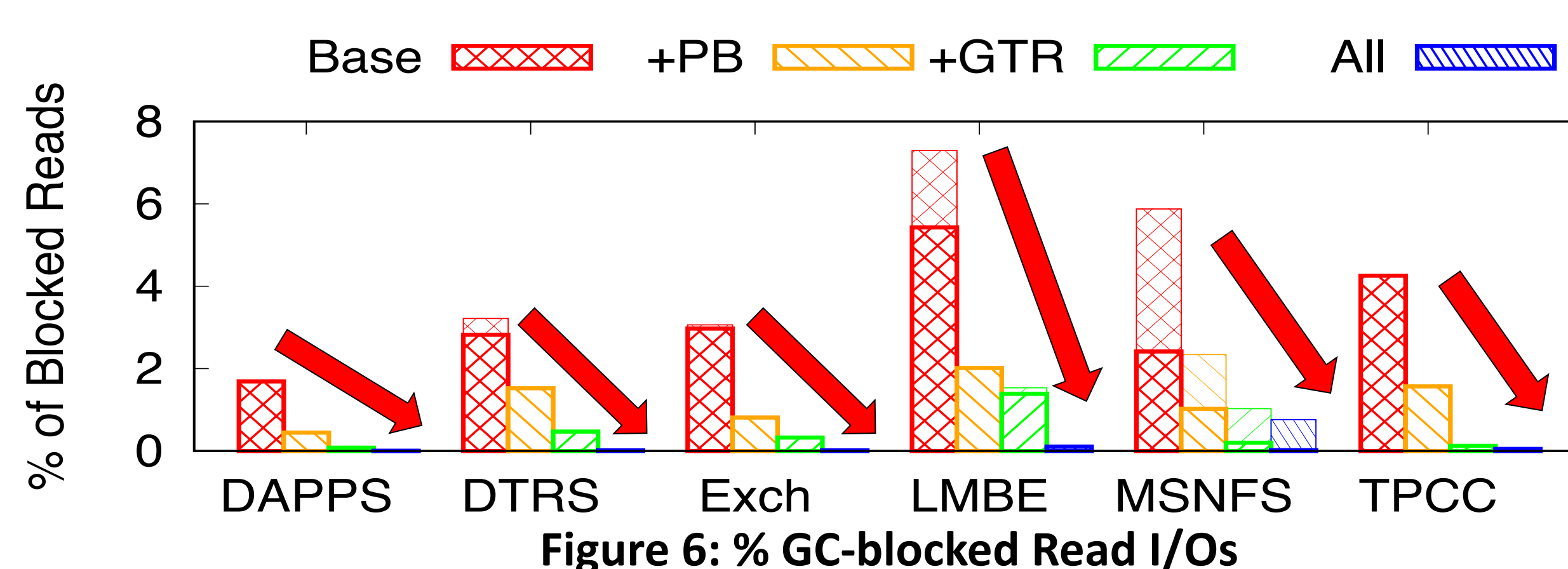


Figure 6: % GC-blocked Read I/Os

Reduced blocked I/Os (total) from 2 – 7% to 0.003 – 0.7%

Average Latencies:

ttFlash is 2.52-7.88x faster than Base (with RAIN) and 1.09-1.33x slower than NoGC (without RAIN).

GC Overheads:

ttFlash introduces 15 – 18% of additional P/E cycles (in 4 out of 6 workloads) due to RAIN (Ideally 1/7 \approx 15%)